National Semiconductor

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LMC7111
Tiny CMOS Operational Amplifier with Rail-to-Rail Input and Output

General Description

The LMC7111 is a micropower CMOS operational amplifier available in the space saving SOT 23-5 package. This makes the LMC7111 ideal for space and weight critical designs. The wide common-mode input range makes it easy to design battery monitoring circuits which sense signals above the V^+ supply. The main benefits of the Tiny package are most apparent in small portable electronic devices, such as mobile phones, pagers, and portable computers. The tiny amplifiers can be placed on a board where they are needed, simplifying board layout.

Features

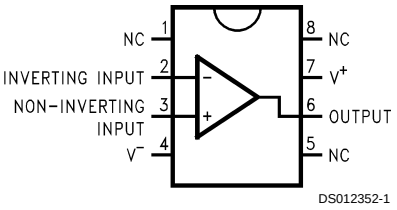
- Tiny SOT23-5 package saves space
- Very wide common mode input range
- Specified at 2.7V, 5V, and 10V
- Typical supply current 25 µA at 5V
- 50 kHz gain-bandwidth at 5V
- Similar to popular LMC6462
- Output to within 20 mV of supply rail at 100k load
- Good capacitive load drive

Applications

- Mobile communications
- Portable computing
- Current sensing for battery chargers
- Voltage reference buffering
- Sensor interface
- Stable bias for GaAs RF amps

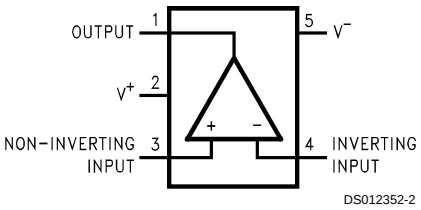
Connection Diagrams

8-Pin DIP



Top View

5-Pin SOT23-5



Top View

Actual Size

Ordering Information

Package	Ordering Information	NSC Drawing Number	Package Marking	Transport Media
8-Pin DIP	LMC7111AIN	N08E	LMC7111AIN	Rails
8-Pin DIP	LMC7111BIN	N08E	LMC7111BIN	Rails
5-Pin SOT23-5	LMC7111BIM5	MA05A	A01B	1k units Tape and Reel
	LMC7111BIM5X	MA05A	A01B	3k Units Tape and Reel

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

ESD Tolerance SOT23-5 (Note 2)	2000V
ESD Tolerance DIP Package (Note 2)	1500V
Differential Input Voltage	±Supply Voltage
Voltage at Input/Output Pin	(V^+) + 0.3V, (V^-) − 0.3V
Supply Voltage $(V^+ - V^-)$	11V
Current at Input Pin	±5 mA
Current at Output Pin (Note 3)	±30 mA
Current at Power Supply Pin	30 mA
Lead Temp. (Soldering, 10 sec.)	260˚C
Storage Temperature Range	−65˚C to +150˚C
Junction Temperature (Note 4)	150˚C

Operating Ratings (Note 1)

Supply Voltage	$2.5V \le V^+ \le 11V$
Junction Temperature Range	
LMC7111AI, LMC7111BI	$-40˚C \le T_J \le +85˚C$
Thermal Resistance (θ_{JA})	
N Package, 8-Pin Molded DIP	115˚C/W
M05A Package, 5-Pin Surface Mount	325˚C/W

2.7V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 2.7V, V^- = 0V, $V_{CM} = V_O = V^+/2$ and R_L > 1 MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
V_{OS}	Input Offset Voltage	V^+ = 2.7V	0.9	3	7	mV
				5	**9**	max
TCV_{OS}	Input Offset Voltage Average Drift		2.0			µV/˚C
I_B	Input Bias Current	(Note 9)	0.1	1	1	pA
				20	**20**	max
I_{OS}	Input Offset Current	(Note 9)	0.01	0.5	0.5	pA
				10	**10**	max
R_{IN}	Input Resistance		>10			Tera Ω
+PSRR	Positive Power Supply Rejection Ratio	2.7V ≤ V^+ ≤5.0V, V^- = 0V, V_O = 2.5V	60	55	55	dB
				50	**50**	min
−PSRR	Negative Power Supply Rejection Ratio	−2.7V ≤ V^- ≤−5.0V, V^- = 0V, V_O = 2.5V	60	55	55	dB
				50	**50**	min
V_{CM}	Input Common-Mode Voltage Range	V^+ = 2.7V For CMRR ≥ 50 dB	−0.10	0.0	0.0	V
				0.40	**0.40**	min
			2.8	2.7	2.7	V
				2.25	**2.25**	max
C_{IN}	Common-Mode Input Capacitance		3			pF
V_O	Output Swing	V^+ = 2.7V R_L = 100 kΩ	2.69	2.68	2.68	V
				2.4	**2.4**	min
			0.01	0.02	0.02	V
				0.08	**0.08**	max
		V^+ = 2.7V R_L = 10 kΩ	2.65	2.6	2.6	V
				2.4	**2.4**	min
			0.03	0.1	0.1	V
				0.3	**0.3**	max
I_{SC}	Output Short Circuit Current	Sourcing, V_O = 0V	7	1	1	mA
				0.7	**0.7**	min
		Sinking, V_O = 2.7V	7	1	1	mA
				0.7	**0.7**	min

2.7V DC Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 2.7V, V^- = 0V, $V_{CM} = V_O = V^+/2$ and $R_L > 1$ MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
A_{VOL}	Voltage Gain	Sourcing	400			V/mv min
		Sinking	150			V/mv min
I_S	Supply Current	V^+ = +2.7V, $V_O = V^+/2$	20	45 **60**	50 **65**	µA max

2.7V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 2.7V, V^- = 0V, $V_{CM} = V_O = V^+/2$ and $R_L > 1$ MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
SR	Slew Rate	(Note 8)	0.015			V/µs
GBW	Gain-Bandwidth Product		40			kHz

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 2: Human body model, 1.5 kΩ in series with 100 pF.

Note 3: Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature at 150˚C.

Note 4: The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

Note 5: Typical Values represent the most likely parametric norm.

Note 6: All limits are guaranteed by testing or statistical analysis.

Note 7: V^+ = 2.7V, V_{CM} = 1.35V and R_L connected to 1.35V. For Sourcing tests, $1.35V \le V_O \le 2.7V$. For Sinking tests, $0.5V \le V_O \le 1.35V$.

Note 8: Connected as Voltage Follower with 1.0V step input. Number specified is the slower of the positive and negative slew rates. Input referred, V^+ = 2.7V and R_L = 100 kΩ connected to 1.35V. Amp excited with 1 kHz to produce $V_O = 1\ V_{PP}$.

Note 9: Bias Current guaranteed by design and processing.

3V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 3V, V^- = 0V, $V_{CM} = V_O = V^+/2$ and $R_L > 1$ MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
V_{CM}	Input Common-Mode Voltage Range	V^+ = 3V For CMRR ≥ 50 dB	−0.25	0.0	0.0	V min
			3.2	3.0 **2.8**	3.0 **2.8**	V max

3.3V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 3.3V, V^- = 0V, $V_{CM} = V_O = V^+/2$ and $R_L > 1$ MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
V_{CM}	Input Common-Mode Voltage Range	V^+ = 3.3V For CMRR ≥ 50 dB	−0.25	−0.1 **0.00**	−0.1 **0.00**	V min
			3.5	3.4 **3.2**	3.4 **3.2**	V max

5V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 5V, V^- = 0V, $V_{CM} = V_O = V^+/2$ and $R_L > 1$ MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
V_{OS}	Input Offset Voltage	V^+ = 5V	0.9			mV max
TCV_{OS}	Input Offset Voltage Average Drift		2.0			µV/˚C
I_B	Input Bias Current	(Note 9)	0.1	1 **20**	1 **20**	pA max
I_{OS}	Input Offset Current	(Note 9)	0.01	0.5 **10**	0.5 **10**	pA max
R_{IN}	Input Resistance		>10			Tera Ω
CMRR	Common Mode Rejection Ratio	0V ≤ V_{CM} ≤ 5V	85	70	60	dB min
+PSRR	Positive Power Supply Rejection Ratio	5V ≤ V^+ ≤10V, V^- = 0V, V_O = 2.5V	85	70	60	dB min
−PSRR	Negative Power Supply Rejection Ratio	−5V ≤ V^- ≤−10V, V^- = 0V, V_O = −2.5V	85	70	60	dB min
V_{CM}	Input Common-Mode Voltage Range	V^+ = 5V For CMRR ≥ 50 dB	−0.3	−0.20 **0.00**	−0.20 **0.00**	V min
			5.25	5.20 **5.00**	5.20 **5.00**	V max
C_{IN}	Common-Mode Input Capacitance		3			pF
V_O	Output Swing	V^+ = 5V	4.99	4.98	4.98	Vmin
		R_L = 100 kΩ	0.01	0.02	0.02	Vmax
		V^+ = 5V	4.98	4.9	4.9	Vmin
		R_L = 10 kΩ	0.02	0.1	0.1	Vmin
I_{SC}	Output Short Circuit Current	Sourcing, V_O = 0V	7	5 **3.5**	5 **3.5**	mA min
		Sinking, V_O = 3V	7	5 **3.5**	5 **3.5**	mA min
A_{VOL}	Voltage Gain	Sourcing	500			V/mv min
		Sinking	200			V/mv min
I_S	Supply Current	V^+ = +5V, $V_O = V^+/2$	25			µA max

5V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 5V, V^- = 0V, V_{CM} = V_O = $V^+/2$ and R_L > 1 MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
SR	Slew Rate	Positive Going Slew Rate (Note 8)	0.027	0.015	0.010	V/µs
GBW	Gain-Bandwidth Product		50			kHz

Note 10: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 11: Human body model, 1.5 kΩ in series with 100 pF.

Note 12: Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature at 150˚C.

Note 13: The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

Note 14: Typical Values represent the most likely parametric norm.

Note 15: All limits are guaranteed by testing or statistical analysis.

Note 16: V^+ = 5V, V_{CM} = 2.5V and R_L connected to 2.5V. For Sourcing tests, 2.5V ≤ V_O ≤ 5.0V. For Sinking tests, 0.5V ≤ V_O ≤ 2.5V.

Note 17: Connected as Voltage Follower with 1.0V step input. Number specified is the slower of the positive slew rate. The negative slew rate is faster. Input referred, V^+ = 5V and R_L = 100 kΩ connected to 1.5V. Amp excited with 1 kHz to produce V_O = 1 V_{PP}.

Note 18: Bias Current guaranteed by design and processing.

10V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 10V, V^- = 0V, V_{CM} = V_O = $V^+/2$ and R_L > 1 MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
V_{OS}	Input Offset Voltage	V^+ = 10V	0.9	3 **5**	7 **9**	mV max
TCV_{OS}	Input Offset Voltage Average Drift		2.0			µV/˚C
I_B	Input Bias Current		0.1	1 **20**	1 **20**	pA max
I_{OS}	Input Offset Current		0.01	0.5 **10**	0.5 **10**	pA max
R_{IN}	Input Resistance		>10			Tera Ω
+PSRR	Positive Power Supply Rejection Ratio	5V ≤ V^+ ≤10V, V^- = 0V, V_O = 2.5V	80			dB min
−PSRR	Negative Power Supply Rejection Ratio	−5V ≤ V^- ≤−10V, V^- = 0V, V_O = 2.5V	80			dB min
V_{CM}	Input Common-Mode Voltage Range	V^+ = 10V For CMRR ≥ 50 dB	−0.2	−0.15 **0.00**	−0.15 **0.00**	V min
			10.2	10.15 **10.00**	10.15 **10.00**	V max
C_{IN}	Common-Mode Input Capacitance		3			pF
I_{SC}	Output Short Circuit Current (Note 9)	Sourcing, V_O = 0V	30	20 **7**	20 **7**	mA min
		Sinking, V_O = 10V	30	20 **7**	20 **7**	mA min

10V DC Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 10V, V^- = 0V, $V_{CM} = V_O = V^+/2$ and $R_L > 1$ MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
A_{VOL}	Voltage Gain 100 kΩ Load	Sourcing	500			V/mv min
		Sinking	200			V/mv min
I_S	Supply Current	V^+ = +10V, $V_O = V^+/2$	25	50 **65**	60 **75**	µA max
V_O	Output Swing	V^+ = 10V	9.99	9.98	9.98	Vmin
		R_L = 100 kΩ	0.01	0.02	0.02	Vmax
		V^+ = 10V	9.98	9.9	9.9	Vmin
		R_L = 10 kΩ	0.02	0.1	0.1	Vmin

10V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V^+ = 10V, V^- = 0V, $V_{CM} = V_O = V^+/2$ and $R_L > 1$ MΩ. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LMC7111AI Limit (Note 6)	LMC7111BI Limit (Note 6)	Units
SR	Slew Rate	(Note 8)	0.03			V/µs
GBW	Gain-Bandwidth Product		50			kHz
ϕ_m	Phase Margin		50			deg
G_m	Gain Margin		15			dB
	Input-Referred Voltage Noise	f = 1 kHz V_{CM} = 1V	110			$\frac{nV}{\sqrt{Hz}}$
	Input-Referred Current Noise	f = 1 kHz	0.03			$\frac{pA}{\sqrt{Hz}}$

Note 19: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 20: Human body model, 1.5 kΩ in series with 100 pF.

Note 21: Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature at 150˚C.

Note 22: The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

Note 23: Typical Values represent the most likely parametric norm.

Note 24: All limits are guaranteed by testing or statistical analysis.

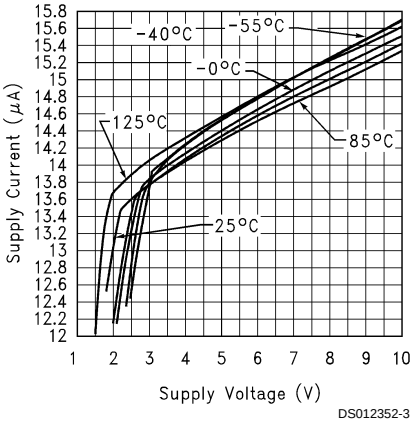
Note 25: V^+ = 10V, V_{CM} = 5V and R_L connected to 5V. For Sourcing tests, 5V ≤ V_O ≤ 10V. For Sinking tests, 0.5V ≤ V_O ≤ 5V.

Note 26: Connected as Voltage Follower with 1.0V step input. Number specified is the slower of the positive and negative slew rates. Input referred, V^+ = 10V and R_L = 100 kΩ connected to 5V. Amp excited with 1 kHz to produce $V_O = 2\ V_{PP}$.

Note 27: Operation near absolute maximum limits will adversely affect reliability.

Typical Performance Characteristics T_A = 25˚C unless specified, Single Supply

Supply Current vs Supply Voltage



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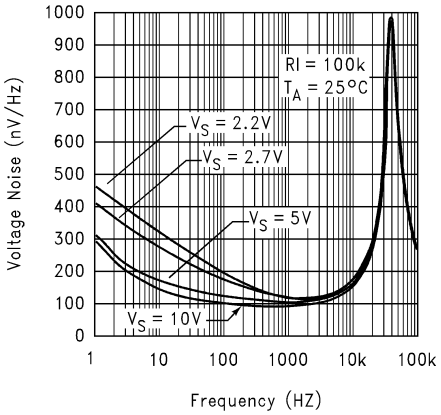
Voltage Noise vs Frequency



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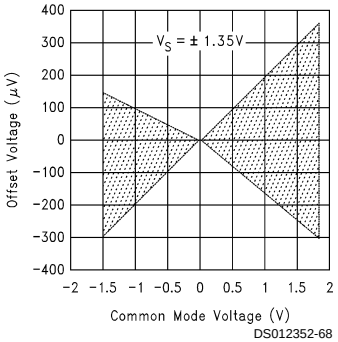
2.7V PERFORMANCE

Offset Voltage vs Common Mode Voltage @ 2.7V



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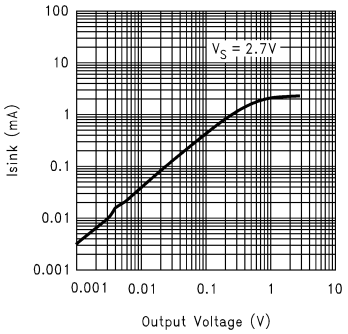
Sinking Output vs Output Voltage



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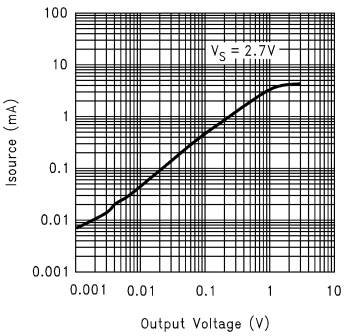
Sourcing Output vs Output Voltage



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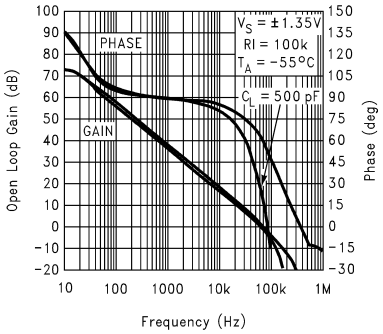
Gain and Phase vs Capacitive Load @ 2.7V



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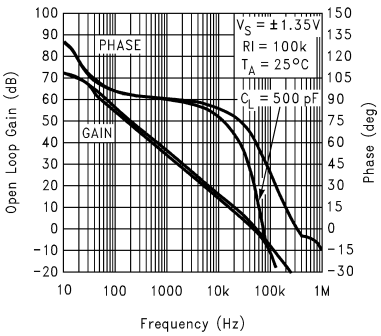
Gain and Phase vs Capacitive Load @ 2.7V



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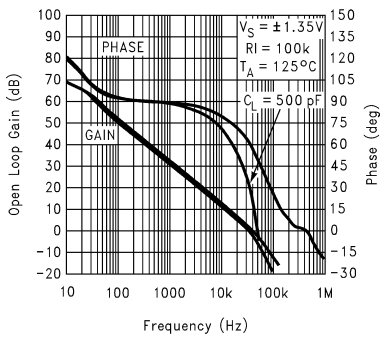
Gain and Phase vs Capacitive Load @ 2.7V



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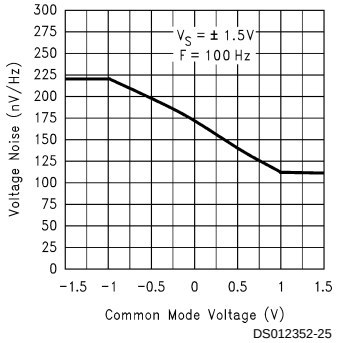
3V PERFORMANCE

Voltage Noise vs Common Mode Voltage @ 3V



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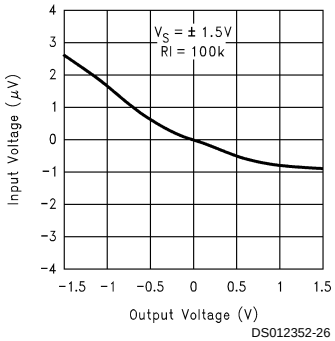
Output Voltage vs Input Voltage @ 3V



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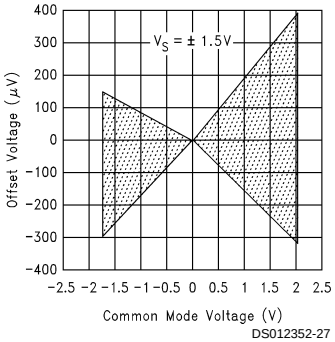
Offset Voltage vs Common Mode Voltage @ 3V



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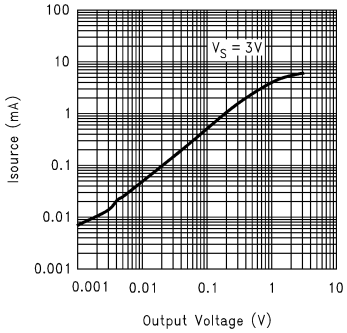
Sourcing Output vs Output Voltage



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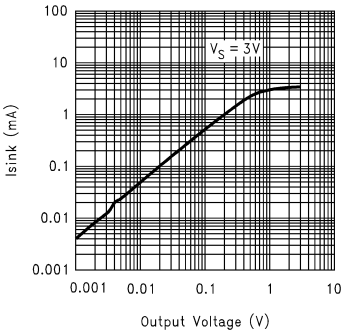
Sinking Output vs Output Voltage



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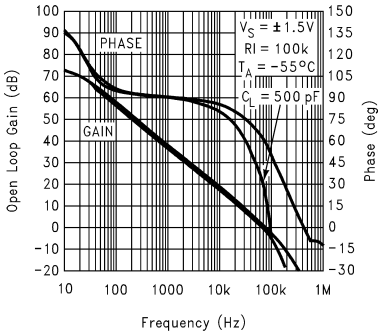
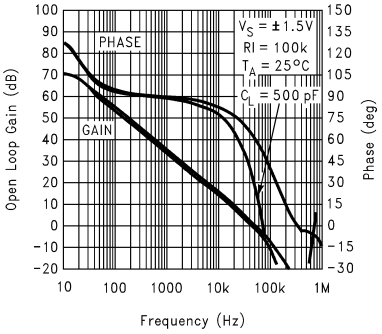
Gain and Phase vs Capacitive Load @ 3V



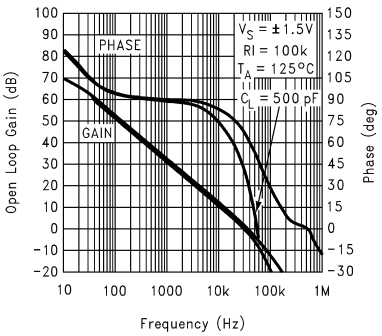
DS012352-30

Gain and Phase vs Capacitive Load @ 3V



DS012352-31

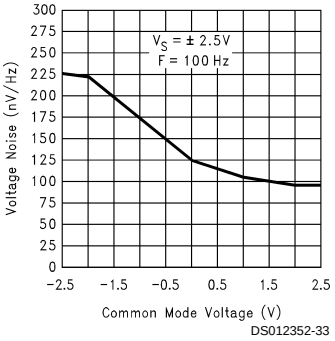
Gain and Phase vs Capacitive Load @ 3V



DS012352-32

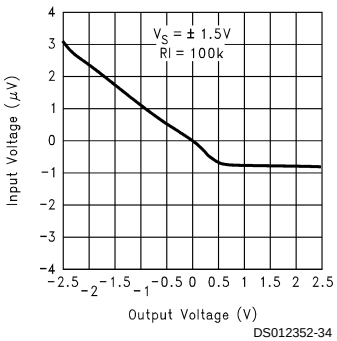
5V PERFORMANCE

Voltage Noise vs Common Mode Voltage @ 5V



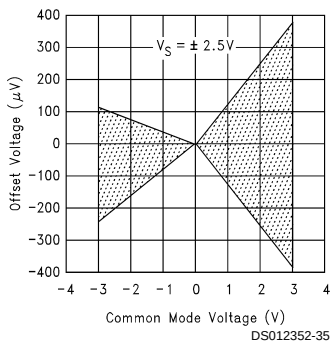
DS012352-33

Output Voltage vs Input Voltage @ 5V



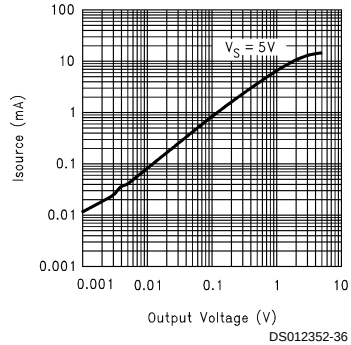
DS012352-34

Offset Voltage vs Common Mode Voltage @ 5V



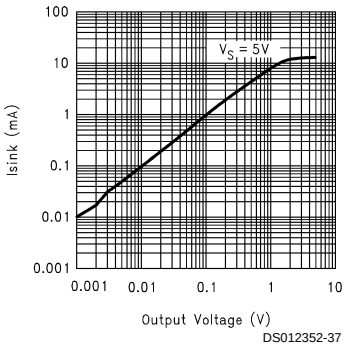
DS012352-35

Sourcing Output vs Output Voltage



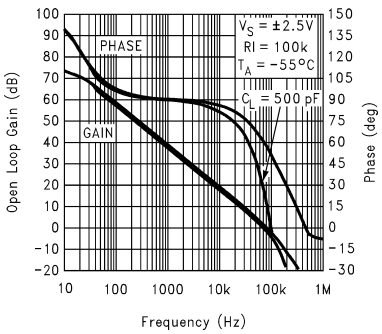
DS012352-36

Sinking Output vs Output Voltage



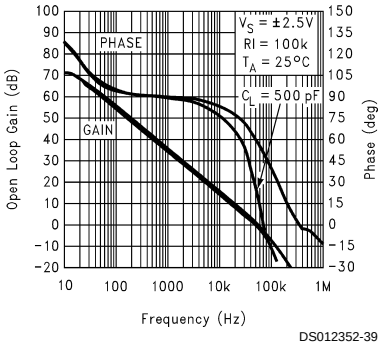
DS012352-37

Gain and Phase vs Capacitive Load @ 5V



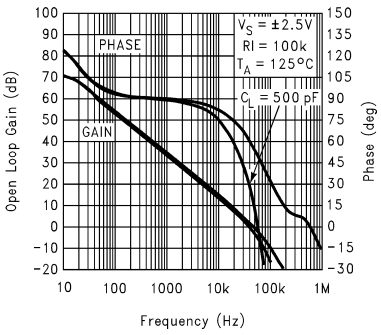
DS012352-38

Gain and Phase vs Capacitive Load @ 5V



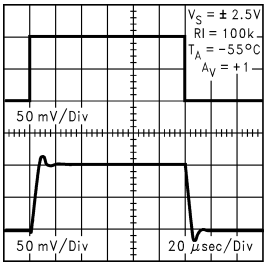
DS012352-39

Gain and Phase vs Capacitive Load @ 5V



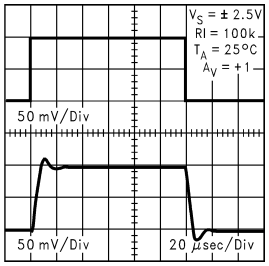
DS012352-40

Non-Inverting Small Signal Pulse Response at 5V



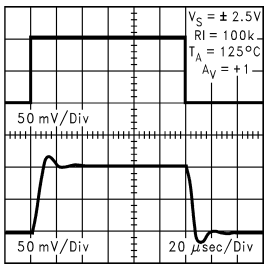
DS012352-41

Non-Inverting Small Signal Pulse Response at 5V



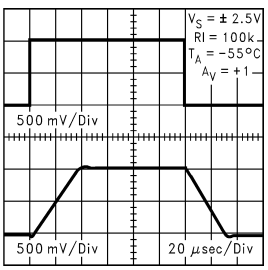
DS012352-42

Non-Inverting Small Signal Pulse Response at 5V



DS012352-43

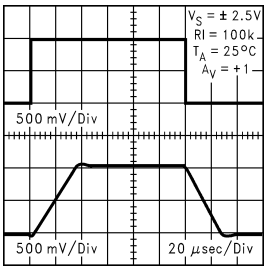
Non-Inverting Large Signal Pulse Response at 5V



DS012352-44

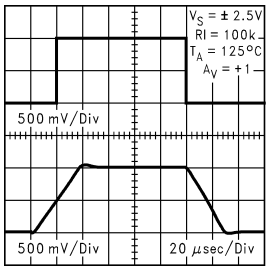
5V PERFORMANCE (Continued)

Non-Inverting Large Signal Pulse Response at 5V



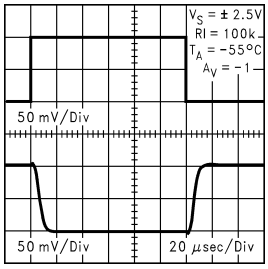
DS012352-45

Non-Inverting Large Signal Pulse Response at 5V



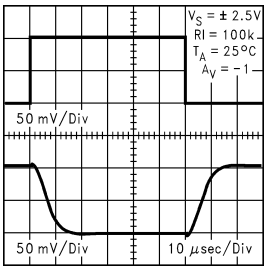
DS012352-46

Inverting Small Signal Pulse Response at 5V



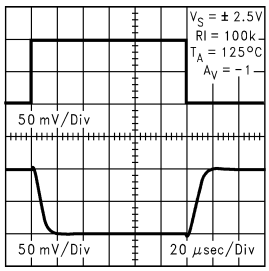
DS012352-47

Inverting Small Signal Pulse Response at 5V



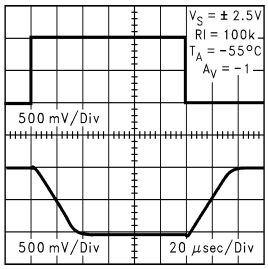
DS012352-48

Inverting Small Signal Pulse Response at 5V



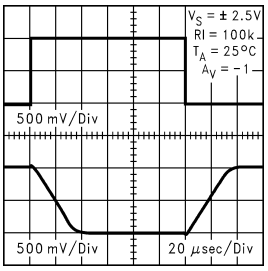
DS012352-49

Inverting Large Signal Pulse Response at 5V



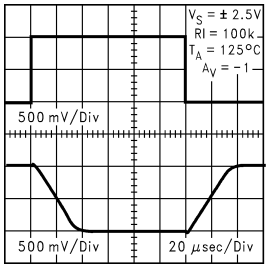
DS012352-50

Inverting Large Signal Pulse Response at 5V



DS012352-51

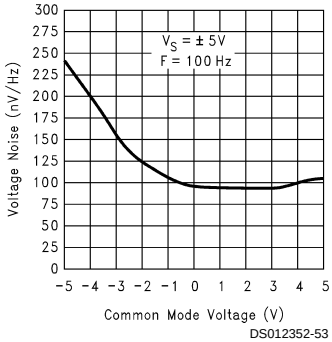
Inverting Large Signal Pulse Response at 5V



DS012352-52

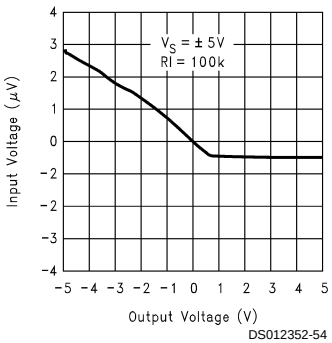
10V PERFORMANCE

Voltage Noise vs Common Mode Voltage @ 10V



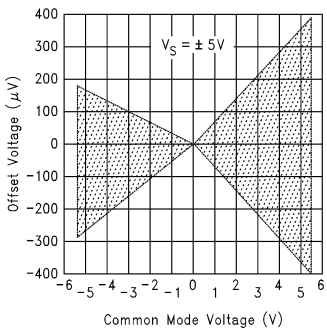
DS012352-53

Output Voltage vs Input Voltage @ 10V



DS012352-54

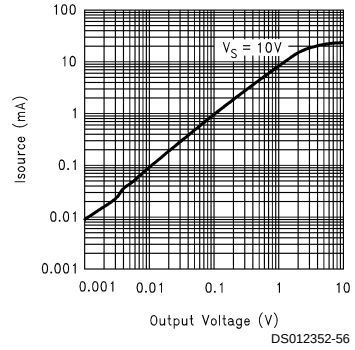
Offset Voltage vs Common Mode Voltage @ 10V



DS012352-55

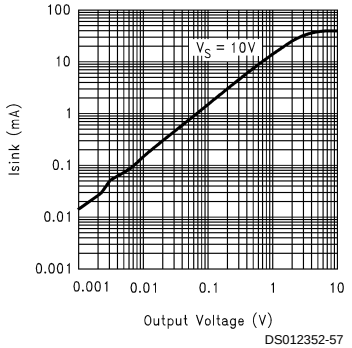
10V PERFORMANCE (Continued)

Sourcing Output vs Output Voltage



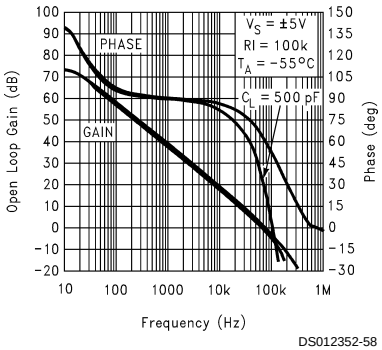
DS012352-56

Sinking Output vs Output Voltage



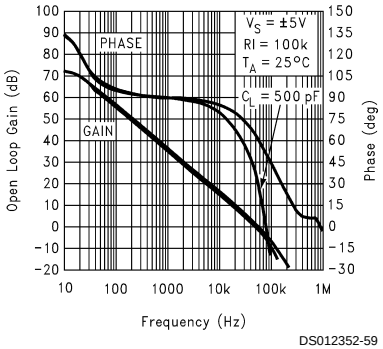
DS012352-57

Gain and Phase vs Capacitive Load @ 10V



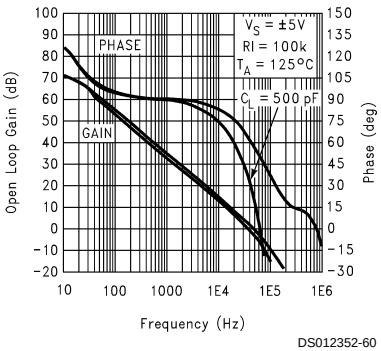
DS012352-58

Gain and Phase vs Capacitive Load @ 10V



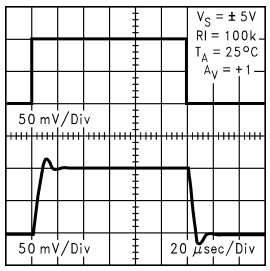
DS012352-59

Gain and Phase vs Capacitive Load @ 10V



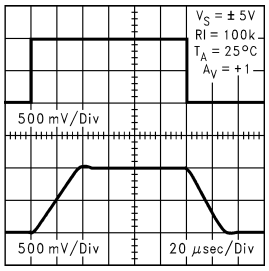
DS012352-60

Non-Inverting Small Signal Pulse Response at 10V



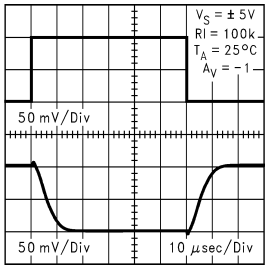
DS012352-61

Non-Inverting Large Signal Pulse Response at 10V



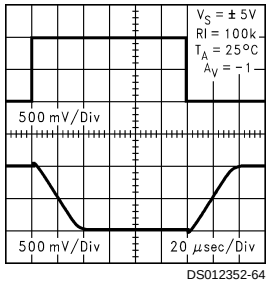
DS012352-62

Inverting Small Signal Pulse Response at 10V



DS012352-63

Inverting Large Signal Pulse Response at 10V



DS012352-64

Application Information

1.0 Benefits of the LMC7111 Tiny Amp

Size. The small footprint of the SOT 23-5 packaged Tiny amp, (0.120 x 0.118 inches, 3.05 x 3.00 mm) saves space on printed circuit boards, and enable the design of smaller electronic products. Because they are easier to carry, many customers prefer smaller and lighter products.

Height. The height (0.056 inches, 1.43 mm) of the Tiny amp makes it possible to use it in PCMCIA type III cards.

Signal Integrity. Signals can pick up noise between the signal source and the amplifier. By using a physically smaller amplifier package, the Tiny amp can be placed closer to the signal source, reducing noise pickup and increasing signal integrity. The Tiny amp can also be placed next to the signal destination, such as a buffer for the reference of an analog to digital converter.

Simplified Board Layout. The Tiny amp can simplify board layout in several ways. First, by placing an amp where amps are needed, instead of routing signals to a dual or quad device, long pc traces may be avoided.

By using multiple Tiny amps instead of duals or quads, complex signal routing and possibly crosstalk can be reduced.

DIPs available for prototyping. LMC7111 amplifiers packaged in conventional 8-pin dip packages can be used for prototyping and evaluation without the need to use surface mounting in early project stages.

Application Information (Continued)

Low Supply Current. The typical 25 µA supply current of the LMC7111 extends battery life in portable applications, and may allow the reduction of the size of batteries in some applications.

Wide Voltage Range. The LMC7111 is characterized at 2.7V, 3V, 3.3V, 5V and 10V. Performance data is provided at these popular voltages. This wide voltage range makes the LMC7111 a good choice for devices where the voltage may vary over the life of the batteries.

2.0 Input Common Mode Voltage Range

The LMC7111 does not exhibit phase inversion when an input voltage exceeds the negative supply voltage.

The absolute maximum input voltage is 300 mV beyond either rail at room temperature. Voltages greatly exceeding this maximum rating can cause excessive current to flow in or out of the input pins, adversely affecting reliability.

Applications that exceed this rating must externally limit the maximum input current to ±5 mA with an input resistor as shown in *Figure 1*.

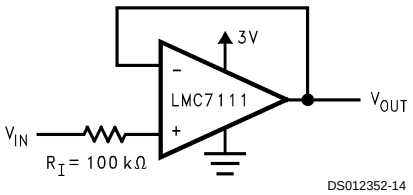


FIGURE 1. R_I Input Current Protection for Voltages Exceeding the Supply Voltage

3.0 Capacitive Load Tolerance

The LMC7111 can typically directly drive a 300 pF load with V_S = 10V at unity gain without oscillating. The unity gain follower is the most sensitive configuration. Direct capacitive loading reduces the phase margin of op-amps. The combination of the op-amp's output impedance and the capacitive load induces phase lag. This results in either an underdamped pulse response or oscillation.

Capacitive load compensation can be accomplished using resistive isolation as shown in *Figure 2*. This simple technique is useful for isolating the capacitive input of multiplexers and A/D converters.

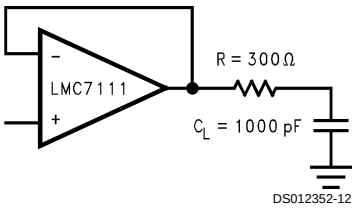


FIGURE 2. Resistive Isolation of a 330 pF Capacitive Load

4.0 Compensating for Input Capacitance when Using Large Value Feedback Resistors

When using very large value feedback resistors, (usually > 500 kΩ) the large feed back resistance can react with the input capacitance due to transducers, photodiodes, and circuit board parasitics to reduce phase margins.

The effect of input capacitance can be compensated for by adding a feedback capacitor. The feedback capacitor (as in *Figure 3*), C_f is first estimated by:

$$\frac{1}{2\pi R_1 C_{IN}} \geq \frac{1}{2\pi R_2 C_f}$$

or

$$R_1 C_{IN} \leq R_2 C_f$$

which typically provides significant overcompensation.

Printed circuit board stray capacitance may be larger or smaller than that of a breadboard, so the actual optimum value for C_F may be different. The values of C_F should be checked on the actual circuit. (Refer to the LMC660 quad CMOS amplifier data sheet for a more detailed discussion.)

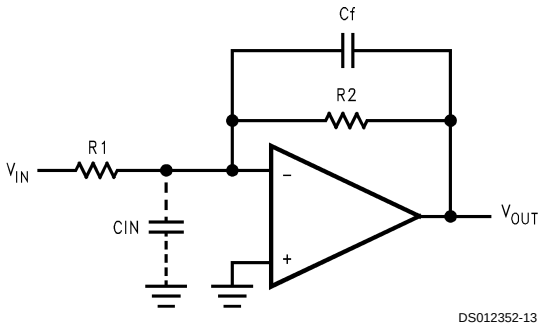


FIGURE 3. Cancelling the Effect of Input Capacitance

5.0 Output Swing

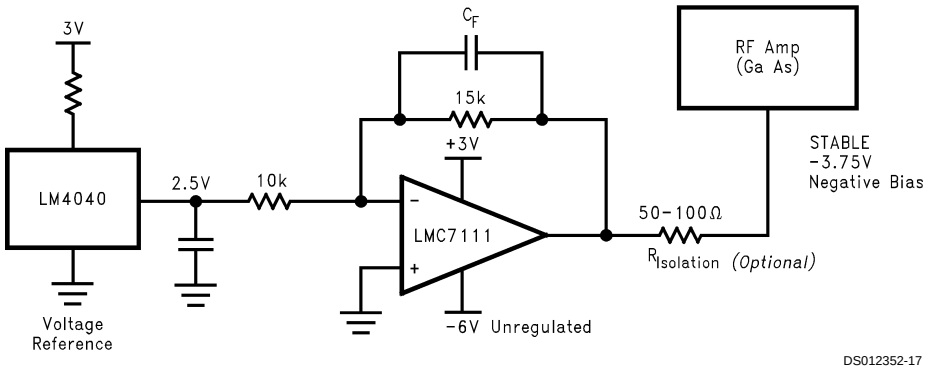
The output of the LMC7111 will go to within 100 mV of either power supply rail for a 10 kΩ load and to 20 mV of the rail for a 100 kΩ load. This makes the LMC7111 useful for driving transistors which are connected to the same power supply. By going very close to the supply, the LMC7111 can turn the transistors all the way on or all the way off.

6.0 Biasing GaAs RF Amplifiers

The capacitive load capability, low current draw, and small size of the SOT23-5 LMC7111 make it a good choice for providing a stable negative bias to other integrated circuits.

The very small size of the LMC7111 and the LM4040 reference take up very little board space.

Application Information (Continued)



C_F and $R_{isolation}$ prevent oscillations when driving capacitive loads.

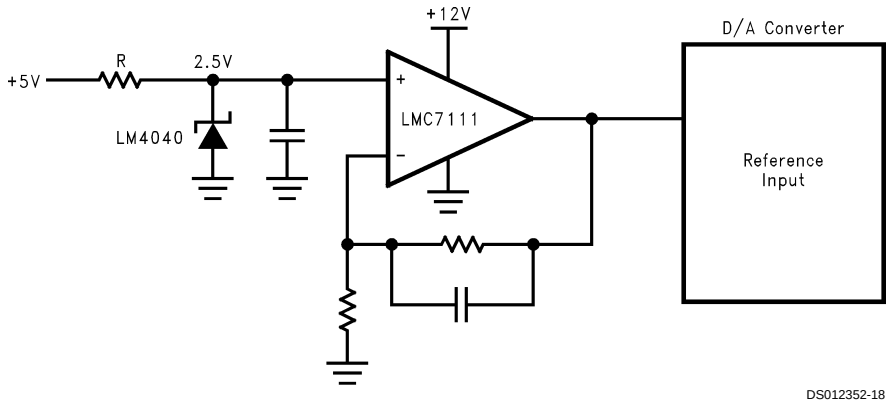
FIGURE 4. Stable Negative Bias

7.0 Reference Buffer for A-to-D Converters

The LMC7111 can be used as a voltage reference buffer for analog-to-digital converters. This works best for A-to-D converters whose reference input is a static load, such as dual slope integrating A-to-Ds. Converters whose reference input is a dynamic load (the reference current changes with time) may need a faster device, such as the LMC7101 or the LMC7131.

The small size of the LMC7111 allows it to be placed close to the reference input. The low supply current (25 µA typical) saves power.

For A-to-D reference inputs which require higher accuracy and lower offset voltage, please see the LMC6462 datasheet. The LMC6462 has performance similar to the LMC7111. The LMC6462 is available in two grades with reduced input voltage offset.



8.0 Dual and Quad Devices with Similar Performance

The LMC6462 and LMC6464 are dual and quad devices with performance similar to the LMC7111. They are available in both conventional through-hole and surface mount packaging. Please see the LMC6462/4 datasheet for details.

9.0 SPICE Macromodel

A SPICE macromodel is available for the LMC7111. This model includes simulation of:

- Input common-mode voltage range
- Frequency and transient response
- Quiescent and dynamic supply current
- Output swing dependence on loading conditions and many more characteristics as listed on the macro model disk. Contact your local National Semiconductor sales office to obtain an operational amplifier spice model library disk.

10.0 Additional SOT23-5 Tiny Devices

National Semiconductor has additional parts available in the space saving SOT23 Tiny package, including amplifiers, voltage references, and voltage regulators. These devices include—

LMC7101 1 MHz gain-bandwidth rail-to-rail input and output amplifier—high input impedance and high gain, 700 µA typical current 2.7V, 3V, 5V and 15V specifications.

LM7131 Tiny Video amp with 70 MHz gain bandwidth. Specified at 3V, 5V and ± 5V supplies.

LMC7211 Comparator in a tiny package with rail-to-rail input and push-pull output. Typical supply current of 7 µA. Typical propagation delay of 7 µs. Specified at 2.7V, 5V and 15V supplies.

LMC7221 Comparator with an open drain output for use in mixed voltage systems. Similar to the LMC7211,

Application Information (Continued)

except the output can be used with a pull-up resistor to a voltage different than the supply voltage.

LP2980 Micropower SOT 50 mA Ultra Low-Dropout Regulator.

LM4040 Precision micropower shunt voltage reference. Fixed voltages of 2.5000V, 4.096V, 5.000V, 8.192V and 10.000V.

LM4041 Precision micropower shunt voltage reference 1.225V and adjustable.

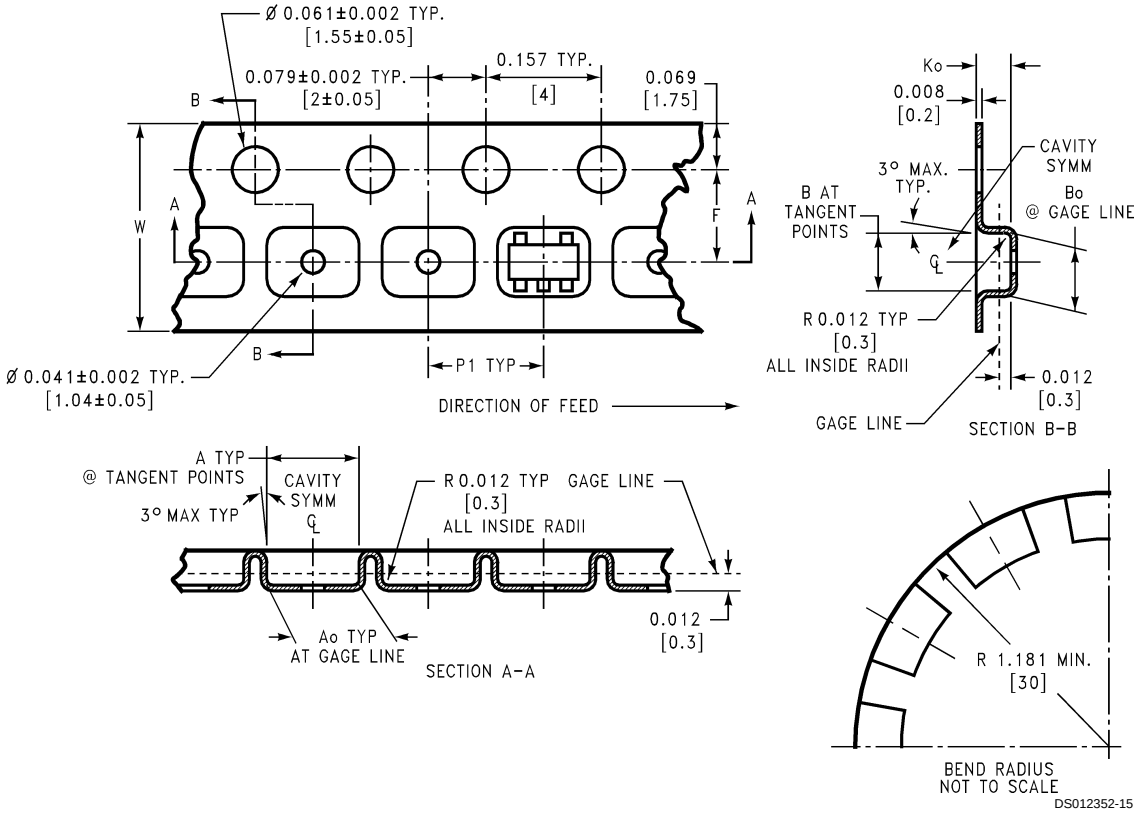
Contact your National Semiconductor representative for the latest information.

SOT-23-5 Tape and Reel Specification

TAPE FORMAT

Tape Section	# Cavities	Cavity Status	Cover Tape Status
Leader	0 (min)	Empty	Sealed
(Start End)	75 (min)	Empty	Sealed
Carrier	3000	Filled	Sealed
	1000	Filled	Sealed
Trailer	125 (min)	Empty	Sealed
(Hub End)	0 (min)	Empty	Sealed

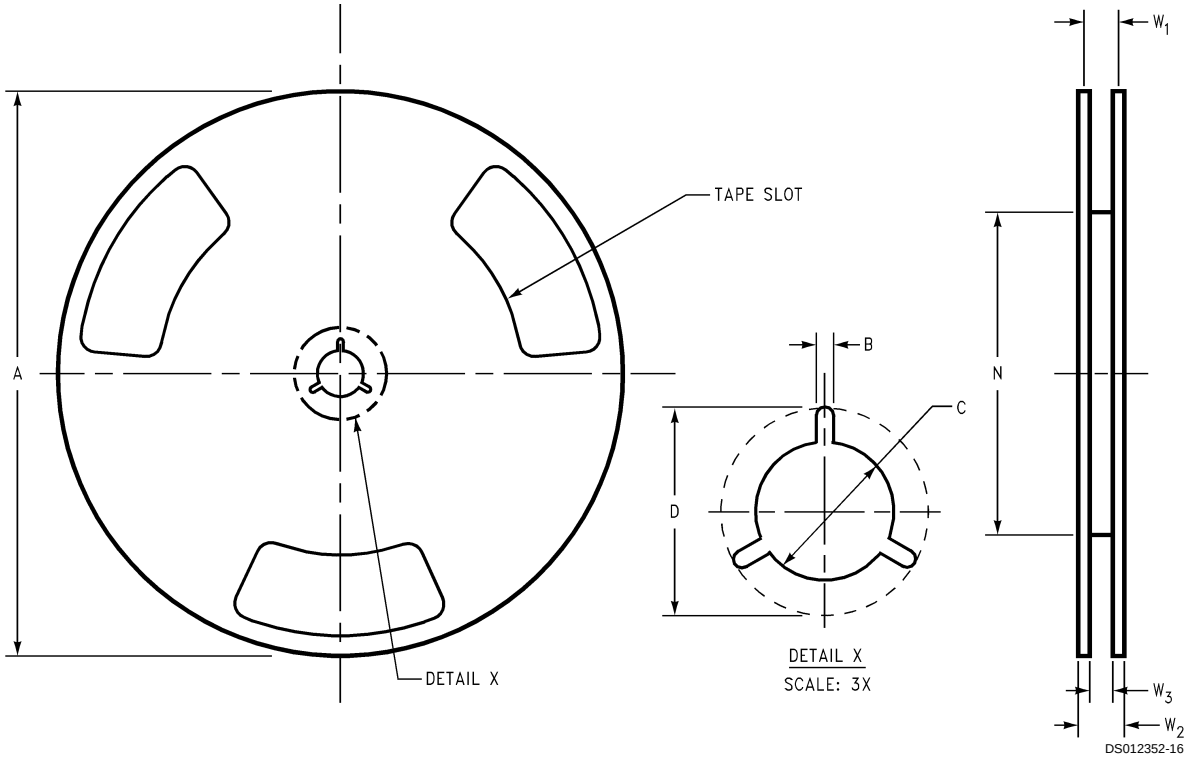
TAPE DIMENSIONS



8 mm	0.130 (3.3)	0.124 (3.15)	0.130 (3.3)	0.126 (3.2)	0.138 ±0.002 (3.5 ±0.05)	0.055 ±0.004 (1.4 ±0.11)	0.157 (4)	0.315 ±0.012 (8 ±0.3)
Tape Size	DIM A	DIM Ao	DIM B	DIM Bo	DIM F	DIM Ko	DIM P1	DIM W

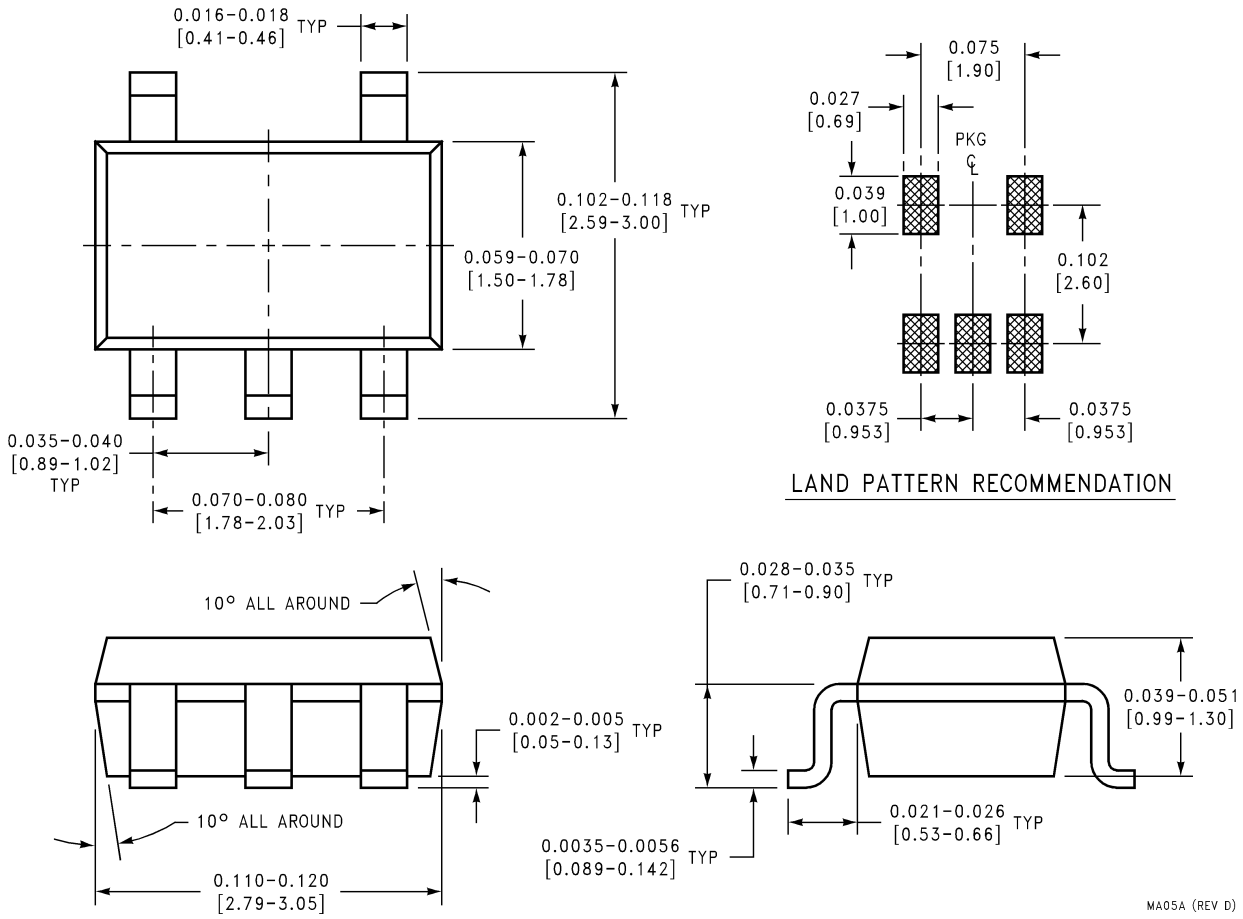
SOT-23-5 Tape and Reel Specification (Continued)

REEL DIMENSIONS



8 mm	7.00 330.00	0.059 1.50	0.512 13.00	0.795 20.20	2.165 55.00	0.331 + 0.059/−0.000 8.40 + 1.50/−0.00	0.567 14.40	W1+ 0.078/−0.039 W1 + 2.00/−1.00
Tape Size	A	B	C	D	N	W1	W2	W3

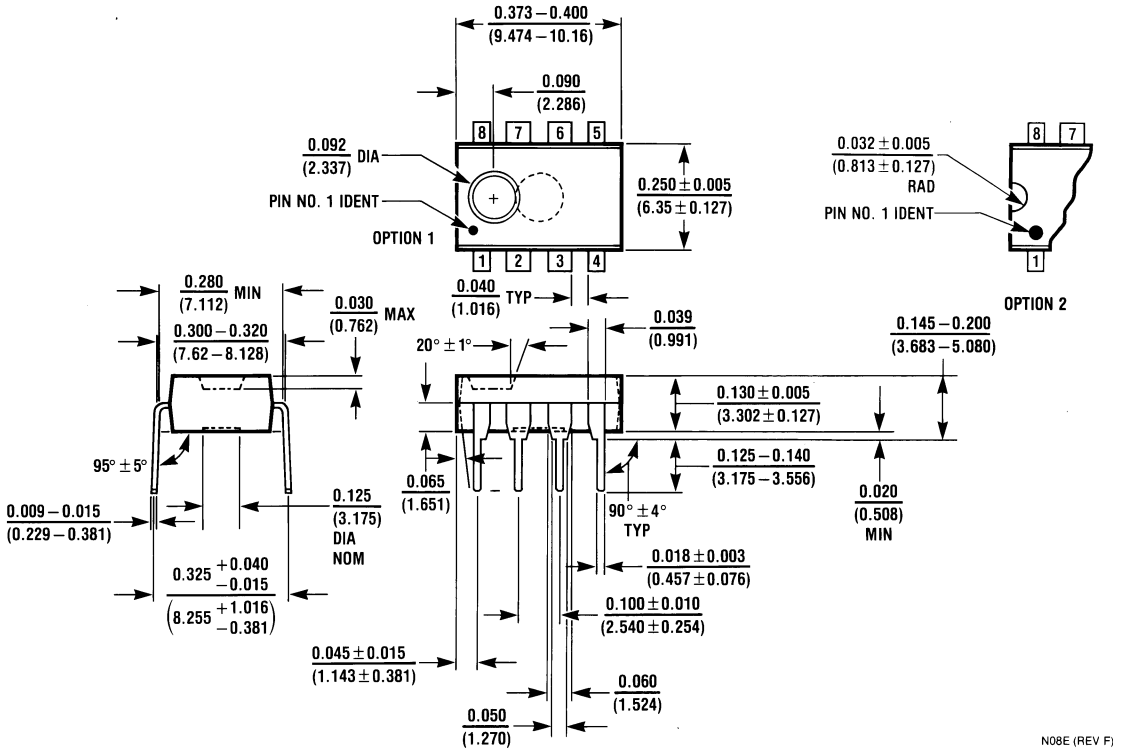
Physical Dimensions inches (millimeters) unless otherwise noted



*Suffix indicates number of units. See Ordering Information on first page.

5-Pin SOT Package
Order Package Number LMC7111BIM5*
NS Package Number MA05A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



8-Pin Molded DIP
8-Lead (0.300" Wide) Molded Dual-In-Line Package
Order Package Number LMC7111AIN or LMC7111BIN
NS Package Number N08E

LIFE SUPPORT POLICY

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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